



# ROITHNER LASERTECHNIK

Wiedner Hauptstraße 76, A-1040 Vienna, Austria

Tel.: +43 1 586 52 43-0, Fax -44, office@roithner-laser.com



## RLT808500G

### TECHNICAL DATA



### High Power Infrared Laserdiode

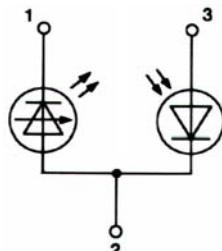
Structure: **High Efficiency MOVCD Quantum Well Design**

Lasing wavelength: **808 nm typ.**

Output power: **500 mW, cw**

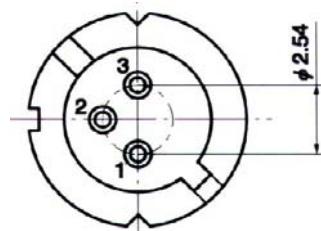
Package: **9 mm**

**NOTE!**  
LASERDIODE  
MUST BE COOLED!



#### PIN CONNECTION:

- 1) Laser diode cathode
- 2) Laser diode anode and photodiode cathode
- 3) Photodiode anode



#### Absolute Maximum Ratings ( $T_c=25^\circ\text{C}$ )

CHARACTERISTIC	SYMBOL	RATING	UNIT
Optical Output Power	$P_o$	550	mW
LD Reverse Voltage	$V_{R(LD)}$	2	V
PD Reverse Voltage	$V_{R(PD)}$	30	V
Operating Temperature	$T_c$	-10 .. +40	$^\circ\text{C}$
Storage Temperature	$T_{STG}$	-40 .. +80	$^\circ\text{C}$

#### Optical-Electrical Characteristics ( $T_c = 25^\circ\text{C}$ )

CHARACTERISTIC	SYMBOL	TEST CONDITION	MIN	TYP	MAX	UNIT
Optical Output Power	$P_o$	kink free		500		mW
Threshold Current	$I_{th}$	cw		150	180	mA
Operation Current	$I_{op}$	$P_o = 500 \text{ mW}$	650	700	750	mA
Operation Voltage	$V_{op}$	$P_o = 500 \text{ mW}$		1.85	2.0	V
Slope Efficiency	$\eta$	cw	0.8	1.0	1.1	W/A
Lasing Wavelength	$\lambda$	$P_o = 500 \text{ mW}$	805	808	811	nm
Beam Divergence	$\theta_{//}$	$P_o = 500 \text{ mW}$	5	9	12	$^\circ$
Beam Divergence	$\theta_{\perp}$	$P_o = 500 \text{ mW}$	30	35	45	$^\circ$
Lasing Aperture	A	$P_o = 500 \text{ mW}$		50x1		$\mu\text{m}^2$
Recommended Operating Temperature	$T_{op}$	cw	20	25	40	$^\circ\text{C}$
Monitor Current	$I_m$	$P_o = 500 \text{ mW}$		0.6	1.5	mA